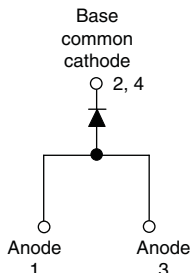


Fast Soft Recovery Rectifier Diode, 80 A



TO-247AC



FEATURES/DESCRIPTION

The 80EPF..PbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for Industrial level and lead (Pb)-free.



RoHS*
COMPLIANT

PRODUCT SUMMARY

V_F at 40 A	< 1.1 V
t_{rr}	70 ns
V_{RRM}	200 to 600 V

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		200 to 600	V
$I_{F(AV)}$	Sinusoidal waveform	80	A
I_{FSM}		1000	
t_{rr}	1 A, - 100 A/μs	70	ns
V_F	40 A, $T_J = 25^\circ\text{C}$	1.1	V
T_J	Range	- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150°C mA
80EPF02PbF	200	300	17
80EPF04PbF	400	500	
80EPF06PbF	600	700	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 95^\circ\text{C}$, 180° conduction half sine wave	80	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	850	
		10 ms sine pulse, no voltage reapplied	1000	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	3610	A^2s
		10 ms sine pulse, no voltage reapplied	5100	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	51 000	$\text{A}^2\sqrt{\text{s}}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

80EPF..PbF Soft Recovery Series

Vishay High Power Products

Fast Soft Recovery
Rectifier Diode, 80 A

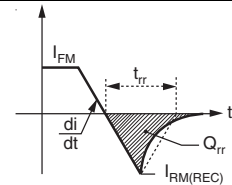


ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	80 A, $T_J = 25\text{ }^{\circ}\text{C}$		1.25	V
Forward slope resistance	r_t	$T_J = 125\text{ }^{\circ}\text{C}$		3.5	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$			0.85	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^{\circ}\text{C}$	$V_R = \text{Rated } V_{RRM}$	0.1	mA
		$T_J = 150\text{ }^{\circ}\text{C}$		17	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 40 Apk 25 A/ μs 25 $^{\circ}\text{C}$	190	ns
Reverse recovery current	I_{rr}		3.4	A
Reverse recovery charge	Q_{rr}		0.5	μC
Snap factor	S		0.5	



THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.35	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		40	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AC	80EPF02	
			80EPF04	
			80EPF06	



80EPF..PbF Soft Recovery Series

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Rectifier Diode, 80 A

Vishay High Power Products

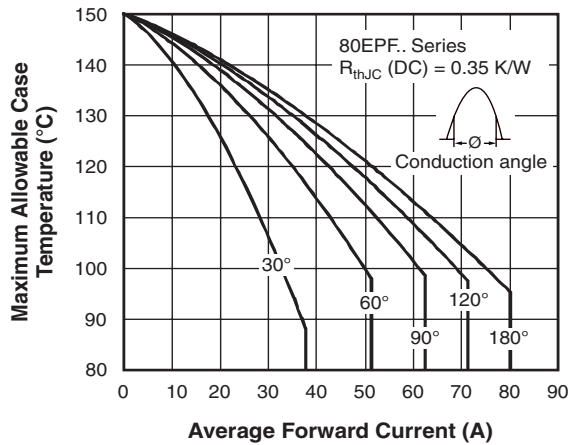


Fig. 1 - Current Rating Characteristics

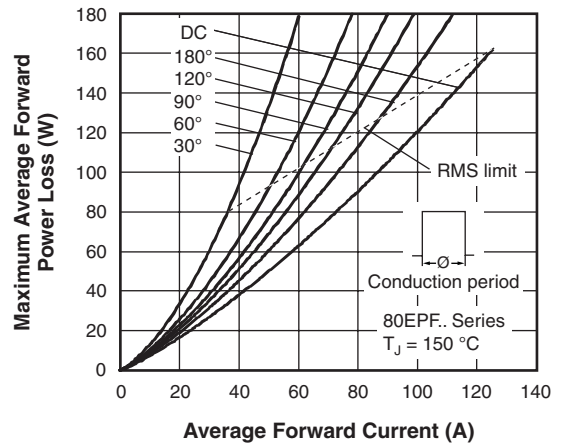


Fig. 4 - Forward Power Loss Characteristics

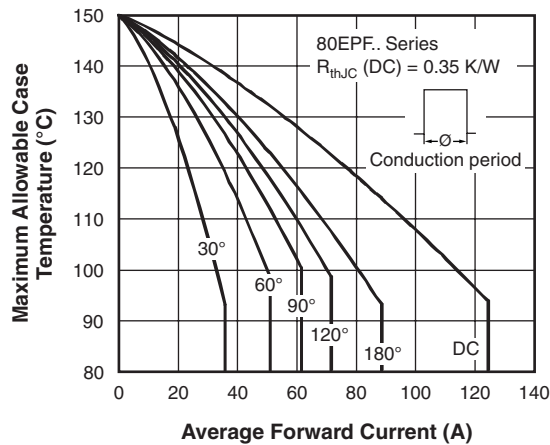


Fig. 2 - Current Rating Characteristics

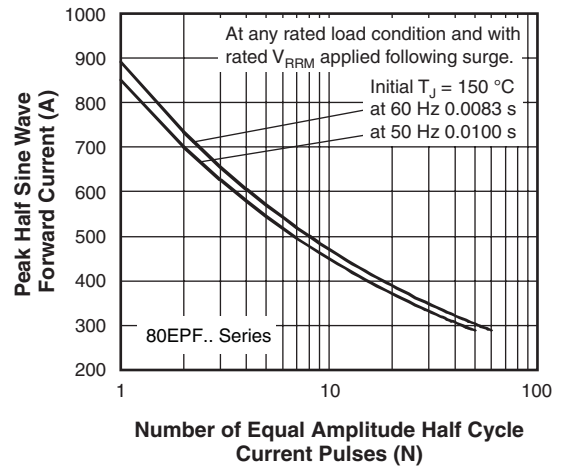


Fig. 5 - Maximum Non-Repetitive Surge Current

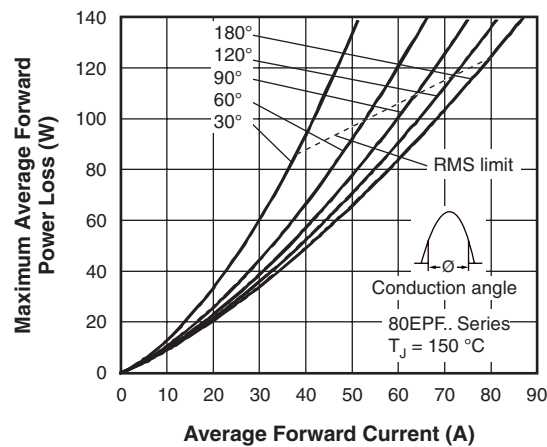


Fig. 3 - Forward Power Loss Characteristics

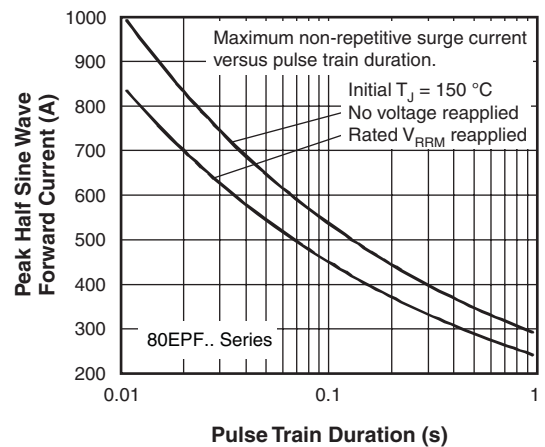


Fig. 6 - Maximum Non-Repetitive Surge Current

80EPF..PbF Soft Recovery Series

Vishay High Power Products

Fast Soft Recovery
Rectifier Diode, 80 A

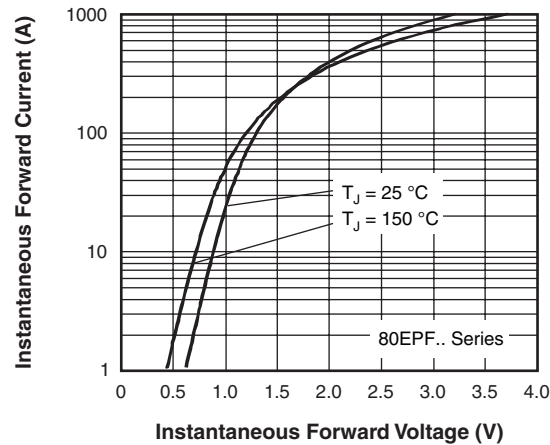


Fig. 7 - Forward Voltage Drop Characteristics

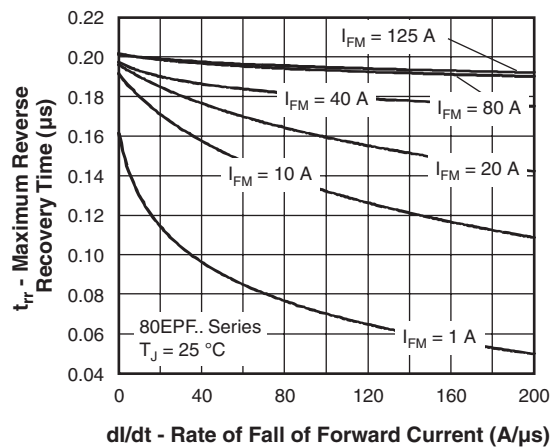


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

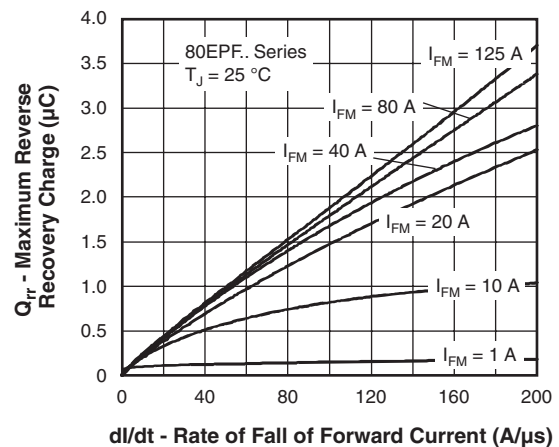


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

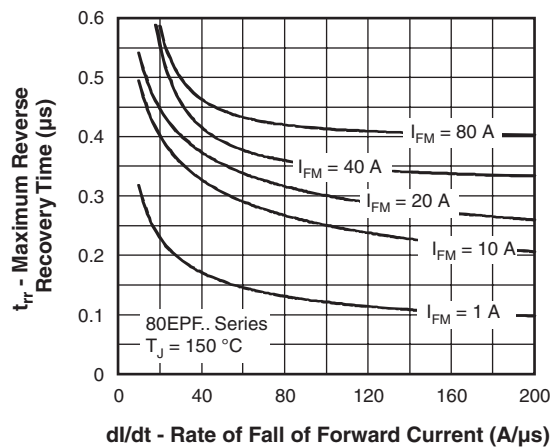


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

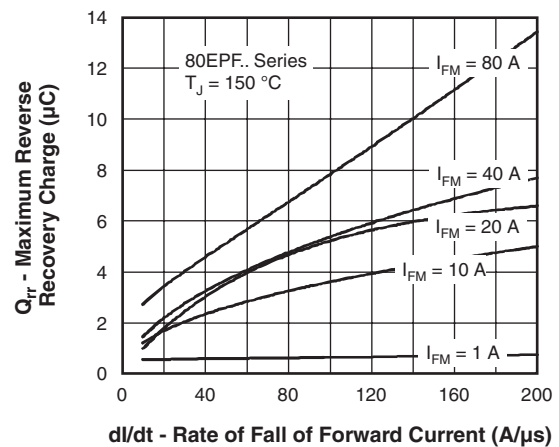


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$



80EPF..PbF Soft Recovery Series

Fast Soft Recovery
Rectifier Diode, 80 A

Vishay High Power Products

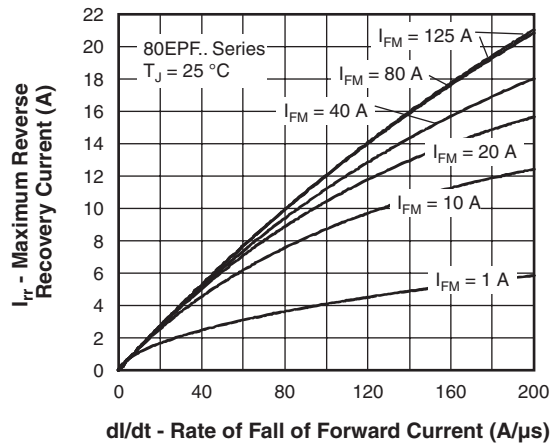


Fig. 12 - Recovery Current Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

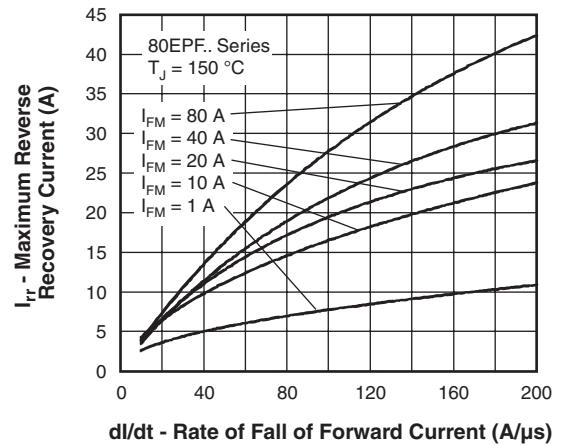


Fig. 13 - Recovery Current Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

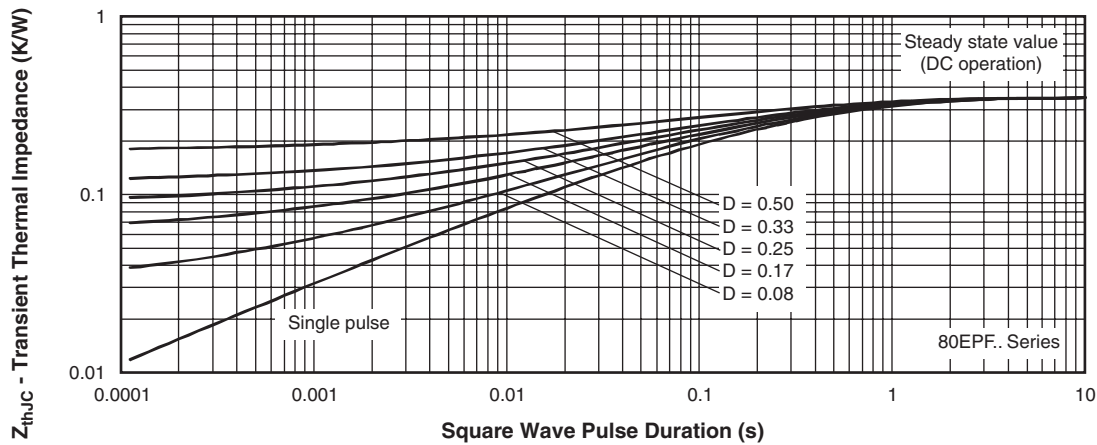


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

80EPF..PbF Soft Recovery Series

Vishay High Power Products

Fast Soft Recovery
Rectifier Diode, 80 A



ORDERING INFORMATION TABLE

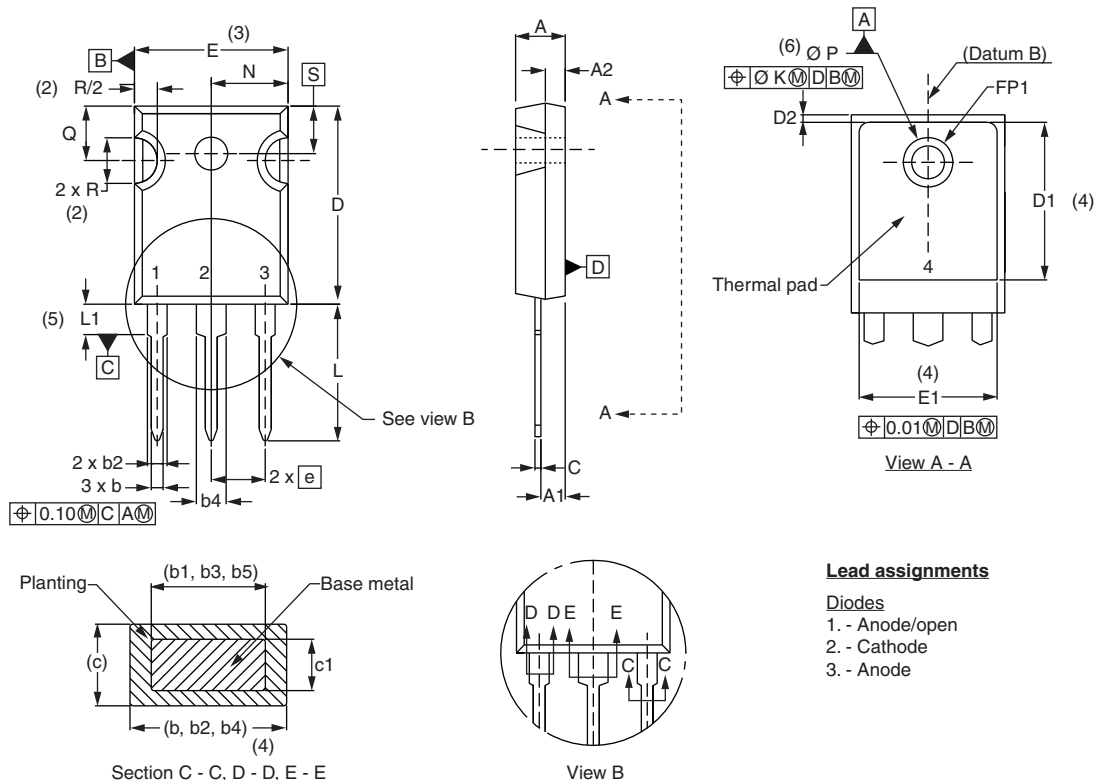
Device code	80	E	P	F	06	PbF
	1	2	3	4	5	6
	1	- Current rating (80 = 80 A)				
	2	- Circuit configuration:				
		E = Single diode				
	3	- Package:				
		P = TO-247AC				
	4	- Type of silicon:				
		F = Fast diode				
	5	- Voltage code x 100 = V_{RRM}				
	6	- • None = Standard production				
		• PbF = Lead (Pb)-free				

02 = 200 V
04 = 400 V
06 = 600 V

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95223
Part marking information	http://www.vishay.com/doc?95226



DIMENSIONS in millimeters and inches



Lead assignments

Diodes

1. - Anode/open
2. - Cathode
3. - Anode

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
e	5.46 BSC		0.215 BSC		
FK	2.54		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62 BSC		0.3		
ΦP	3.56	3.66	0.14	0.144	
$\Phi P1$	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) ΦP to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



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